



JST80T-1600BW 80A TRIAC

Rev.A.1.0

DESCRIPTION:

The JST80T-1600BW triac is suitable for general purpose AC switching. It can be used as an ON/OFF function in applications such as heating regulation, induction motor starting circuits, for phase control operation in light dimmers, motor speed controllers. JST80T-1600BW snubberless triac is especially recommended for use on inductive loads. By using a DBC, JST80T-1600BW provides a rated insulation voltage of 2500 VRMS, complying with UL standards (File ref: E252906). Package TG-C is RoHS compliant.

MAIN FEATURES

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Storage junction temperature range	T_{stg}	-40-150	
Operating junction temperature range	T_j	-40-125	
Repetitive peak off-state voltage ($T_j=25^\circ\text{C}$)	V_{DRM}	1600	V
Repetitive peak reverse voltage ($T_j=25^\circ\text{C}$)	V_{RRM}	1600	V
RMS on-state current ($T_c=89^\circ\text{C}$)	$I_{T(RMS)}$	80	A
Non repetitive surge peak on-state current (full cycle, $t_p=20\text{ms}$, $T_j=25^\circ\text{C}$) Non repetitive surge peak on-	I_{TSM}	800	A

Peak gate power	P_{GM}	25	W
Peak pulse voltage ($T_j=25$; non-repetitive,off-state;FIG.7)	V_{pp}	1	kV

ELECTRICAL CHARACTERISTICS($T_j=25$ unless otherwise specified)

Symbol	Test Condition	Quadrant	Value		Unit
I_{GT}	$V_D=12V R_L=33$	- -	MAX.	50	mA
V_{GT}		- -	MAX.	1.3	V
V_{GD}	$V_D=V_{DRM} T_j=125$ $R_L=3.3k$	- -	MIN.	0.2	V
I_L	$I_G=1.2I_{GT}$	-	MAX.	80	mA
				120	
I_H	$I_T=1A$		MAX.	70	mA
dV/dt	$V_D=1070V$ Gate Open $T_j=125$		MIN.	1500	V s
(dI/dt) _c	$j=125$		MIN.	28	A/ms
t_{on}	$I_G=10mA I_A=200mA I_R=20mA$ $T_j=25$		TYP.	12	s
t_{off}				80	

STATIC CHARACTERISTICS

Symbol	Parameter	Value(MAX.)	Unit
--------	-----------	-------------	------

ORDERING INFORMATION

	J	ST	80	T	-1600	BW
JieJie Microelectronics Co., Ltd.		Triacs				
		$I_{T(RMS)}:80A$				
				$T: TG-C(Ins)$		
						$BW: I_{GT1-3} \ 50mA$
					$1600: V_{DRM} / V_{RRM} \ 1600V$	

MARKING

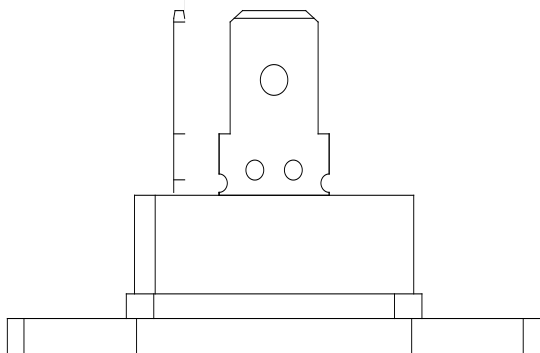


FIG.1: Maximum power dissipation versus RMS on-state current

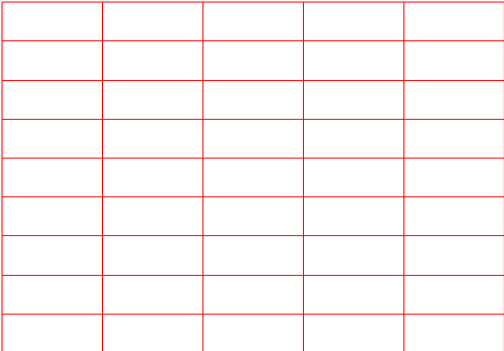
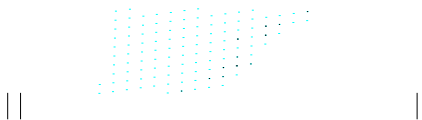


FIG.2: RMS on-state current versus case temperature



PACKAGE MECHANICAL DATA



Information furnished in this document is believed to be accurate and reliable. However, Jiangsu JieJie Microelectronics Co., Ltd. assumes no responsibility for the consequences of use without consideration for such information nor use beyond it. Information mentioned in this document is subject to change without notice, apart from that when an agreement is signed, Jiangsu JieJie complies with the agreement.

Products and information provided in this document have no infringement of patents. Jiangsu JieJie assumes no responsibility for any infringement of other rights of third parties which may result from the use of such products and information. This document supersedes and replaces all information previously supplied.



is a registered trademark of Jiangsu JieJie Microelectronics Co., Ltd.

Copyright © 2023 Jiangsu JieJie Microelectronics Co., Ltd. All rights reserved.